

Effects of carrier concentration on the superfluid density of high- T_c cuprates

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The absolute values and temperature, T , dependence of the in-plane magnetic penetration depth, λ_{ab} , of $\text{La}_{2-x}\text{Sr}_x\text{CuO}_4$ and $\text{HgBa}_2\text{CuO}_{4+\delta}$ have been measured as a function of carrier concentration. We find that the superfluid density, ρ_s , changes substantially and systematically with doping. The values of $\rho_s(0)$ are closely linked to the available low energy spectral weight as determined by the electronic entropy just above T_c and the initial slope of $\rho_s(T)/\rho_s(0)$ increases rapidly with carrier concentration. The results are discussed in the context of a possible relationship between ρ_s and the normal-state (or pseudo) energy gap.

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Superconductivity arises from the binding of electrons into Cooper pairs thereby forming a superfluid with a superconducting energy gap, Δ , in the single-particle excitation spectrum. In high-temperature superconductors (HTS) Δ has essentially $d_{x^2-y^2}$ symmetry in k -space with $\Delta_k = \Delta_0 \cos(2\phi)$ [1], where $\phi = \arctan(k_y/k_x)$ and Δ_0 is the superconducting gap amplitude which will in general be ϕ dependent. Changes in carrier concentration affect the superconducting [2-8] and normal state (NS) [4-7] properties of HTS and there is evidence [3-7] that in addition to Δ_k there is a normal state (or pseudo) gap, Δ_N , in the NS energy excitation spectrum in under- and optimally doped samples which increases with decreasing doping. The maximum gap amplitude shows little variation with underdoping even though T_c is reduced [3-8], in disagreement with the standard mean-field Bardeen-Cooper-Schrieffer (BCS) theory. This unusual behaviour is probably linked to the presence of Δ_N [7]. However, fundamental problems such as the origin of Δ_N and its possible effect on the superfluid density, ρ_s , have not been clearly resolved experimentally or theoretically.

The physical quantity most directly associated with ρ_s is the magnetic penetration depth λ . Appropriate systems to investigate ρ_s as a function of doping are $\text{La}_{2-x}\text{Sr}_x\text{CuO}_4$ and $\text{HgBa}_2\text{CuO}_{4+\delta}$. Both have a simple crystal structure with one CuO_2 plane per unit cell, can have their carrier concentration controlled, and there is experimental evidence suggesting the presence of Δ_N which closes with doping [3-5,9]. Here we report in-plane penetration depth, λ_{ab} , measurements for high-quality $\text{La}_{2-x}\text{Sr}_x\text{CuO}_4$ (LSCO) with $x = 0.10, 0.15, 0.20, 0.22, 0.24$ measured by the ac-susceptibility (*acs*) and muon spin relaxation (μSR) techniques and for $\text{HgBa}_2\text{CuO}_{4+\delta}$ (Hg-1201) with $\delta = 0.10, 0.37$ measured only by μSR . We find systematic changes in ρ_s with carrier concentration

and a correlation with Δ_N .

Single-phase polycrystalline samples of LSCO were prepared in Cambridge using solid-state reaction procedures. No other phases were detected by powder x-ray diffraction and the phase purity is thought to be better than 1%. Lattice parameters were in good agreement with published work [10]. High field magnetic susceptibility measurements showed no signatures of excess paramagnetic centres. The measured T_c 's are 30, 37.7, 36, 27.5 and 20.3 K for $x = 0.10, 0.15, 0.20, 0.22$ and 0.24, respectively. These values are also in very good agreement with previous measurements [10]. μSR experiments as a function of T were performed on the same powders for $x = 0.10$ and 0.15. Although unoriented powders can be used to determine λ_{ab} by μSR [2], the *acs* technique requires the powders to be magnetically aligned [11]. To eliminate grain agglomerates, powders were ball-milled in ethanol and dried after adding a defloculant. Scanning electron microscopy confirmed the absence of grain boundaries and showed that the average grain diameter was $\sim 5\mu\text{m}$. The powders were mixed with a 5 min curing epoxy and aligned in a static field of 12T at room temperature. Debye-Scherrer x-ray scans showed that $\sim 90\%$ of the grains were aligned within $\sim 2.0^\circ$. Low-field susceptibility measurements were performed at an *ac*-field $H_{ac} = 1$ G rms (parallel to the *c*-axis) and a frequency $f = 333$ Hz down to 1.2K. Details of the application of London's model for deriving λ from the measured susceptibility can be found in an earlier publication [11]. Transverse-field-cooled μSR experiments were performed at 400 Gauss in the ISIS, Rutherford-Appleton Laboratory. The field produced a flux-line lattice whose field distribution was probed by muons. The depolarisation rate, $\sigma(T)$, of the initial muon spin is proportional to $\lambda_{ab}^{-2}(T)$ [2,12]. Checks were made to ensure that the

values of λ_{ab} obtained were independent of the applied field. The Hg-1201 [$\delta = 0.10$ ($T_c = 60\text{K}$) and 0.37 ($T_c = 35\text{K}$)] samples were prepared in Houston by the controlled solid-vapour reaction technique [13].

The values of $\lambda_{ab}(0)$ derived from the *acs* data for LSCO are 0.28, 0.26, 0.197, 0.193, 0.194 μm for $x = p = 0.10, 0.15, 0.20, 0.22$ and 0.24 , respectively. Here p is the hole content per planar copper atom. The estimated error for $\lambda_{ab}(0)$ obtained by the *acs* technique is $\pm 15\%$ and within this uncertainty the $\lambda_{ab}(0)$ values agree with the μSR measurements. We thus find that $\lambda_{ab}^{-2}(0)$ is strongly suppressed on the underdoped side, including optimal doping, but there is no suppression with increasing overdoping (up to $p = 0.24$) in contrast to reports for $\text{Ti}_2\text{Ba}_2\text{CuO}_{6+\delta}$ [14]. Values of $\lambda_{ab}(0)$ as obtained by μSR for Hg-1201 are 0.194 and 0.148 μm for $\delta = 0.10$ and 0.37 , respectively. We note that $\delta = 0.10$ and 0.37 in Hg-1201 correspond to $p = 0.075$ and 0.22 , respectively [15].

The T-dependence of λ_{ab} for LSCO is shown in Fig. 1(a) as a plot of $[1/\lambda_{ab}(T)]^2 \propto \rho_s(T)$. Data for $x = 0.10$ and 0.15 obtained by μSR are also included for comparison. Overall there is good agreement between the results from the two techniques. From the *acs* data we find that the initial linear term in $\lambda_{ab}(T)$, characteristic of a clean d-wave superconductor, persists up to the highest doping measured ($x = 0.24$) in agreement with electronic specific heat studies on polycrystalline LSCO samples from the same batch as those studied here [16]. Figure 1(b) depicts data for Hg-1201 powders measured only by μSR , including data from Ref. [17] for a Hg-1201 sample (also from Houston) with $\delta = 0.154$ ($p = 0.17$). As in LSCO, we observe a change in the shape of $\sigma(T) \propto [1/\lambda_{ab}(T)]^2$ of Hg-1201 with doping. Namely, in the underdoped region $[1/\lambda_{ab}(T)]^2$ shows a more pronounced curvature. Taking the slope of the low-T linear term to be proportional to $\rho_s(0)/\Delta_0$ the observed trend of $[1/\lambda_{ab}(T)]^2$ with p would imply that Δ_0 remains approximately constant in the underdoped region and decreases rapidly with overdoping.

Figure 2 shows a comparison of the present results for LSCO with specific heat data taken on the same samples [16] where Δ_N was observed for $x = p < 0.19$. In the inset we observe a good correlation between $[1/\lambda_{ab}(0)]^2$ and $[S/T(T_c) - S/T(2\text{K})]$ both plotted versus Sr content x , where $S(T)$ is the electronic entropy obtained by integrating the electronic specific heat coefficient $\gamma(T)$ from 0 to T . The quantity $[S/T(T_c) - S/T(2\text{K})]$ is a measure of the energy-dependent NS electronic density of states (DOS), $g_n(E)$, averaged over $\pm 2k_B T_c$ around the Fermi energy E_F . The effect of an energy-dependent DOS on the London penetration depth λ_L or $\rho_s(0)$ is not usually considered in standard theory which implicitly assumes a constant DOS and a parabolic $E(\vec{k})$ dispersion relation. It has been argued elsewhere [5] that $\rho_s(0) = 4\pi^2 \langle v_x^2 g_n(E) \rangle / e^2$ where the average is over an (anisotropic) energy shell $E_F \pm \Delta_0$. Note that this result

agrees with the standard expression for the NS conductivity and the usual relation between $\lambda_L(0)$ and the real part of the frequency-dependent electronic conductivity in the normal and superconducting states $\sigma_1^n(\omega)$ and $\sigma_1^s(\omega)$, respectively. Namely, $\lambda_L(0)$ is determined by the area under the $[\sigma_1^n(\omega) - \sigma_1^s(\omega)]$ curve in the frequency range $0 < h\omega/2\pi < 2\Delta_0$. Thus the inset to Fig. 2 suggests that the strong decrease of $\rho_s(0)$ with x from $x = 0.20$ to 0.10 is related to the suppression of spectral weight with energy range $E_F \pm \Delta_0$ due to the presence of Δ_N .

The main panel in Fig. 2 shows a correlation between the doping dependence of the initial linear terms of $\lambda_{ab}(T)$ and the low-T specific heat coefficient γ , both quantities being related to the number of excited quasiparticles $n_e(T)$. For low values of x , $n_e(T=10)$ is much smaller than expected from the T_c value and this probably implies that the average value of $\Delta_0(\phi)$ is significantly larger than T_c . The rapid rise above $x = 0.20$ may arise from the combined effects of the closure of Δ_N at $x = 0.19$ [4,16], the decreasing T_c plus the fact that for LSCO there is significant pile up of states near E_F in the overdoped region $0.20 < x < 0.35$ [16].

In Fig. 3(a) we present the LSCO *acs* data as $[\lambda_{ab}(0)/\lambda_{ab}(T)]^2$ versus T/T_c and compare the data with the mean-field calculation for a d-wave weak-coupled BCS superconductor with a cylindrical Fermi surface (FS) which gives $\Delta_0/T_c \sim 2.14$ [18]. There appears to be a systematic deviation of the data from the weak-coupling T-dependence with a greater (weaker) curvature on the underdoped (overdoped) side. We note however, that particularly in the overdoped samples there is positive curvature near T_c which may arise from a small amount of doping inhomogeneity giving a distribution of T_c values in this region where dT_c/dp is maximal [10]. The effect of this is to rescale the curves with a slightly lower value of T_c . We have modelled $\rho_s(T)$ using the d-wave T-dependence and a normal distribution of T_c values with standard deviation of 3%, 5% and 9% for $x = 0.20, 0.22$ and 0.24 , respectively. These corrections, plotted in Fig. 3(b), bring the curves for $x = 0.20$ and 0.22 into good agreement with weak-coupling BCS with $\Delta_0/T_c \sim 2.14$. Similar deductions, as to the magnitude and p-dependence of Δ_0/T_c , were made in the specific heat studies on these overdoped samples [16]. However, the $x = 0.24$ sample still shows significant deviations that possibly reflect changes in the electronic structure. This would not be surprising given the changes in the FS with the rapid crossover from hole-like to electron-like states near $x = 0.27$ [19]. We note that the data for $x = 0.24$ is in excellent agreement with a weak-coupling d-wave calculation for a rectangular FS [20].

In contrast to the overdoped samples the optimal and underdoped samples [Fig. 3(a)], both possessing very small rounding near T_c , diverge significantly from the weak-coupling curve and in the opposite direction. We

note that accounting for inhomogeneities in these samples will, if anything, move the curves even further from the weak-coupling BCS fit.

A central conclusion of the present work is that there is a crossover in both $\rho_s(0)$ and $\rho_s(T)$ near $p = 0.20$. Such behaviour is characteristic of many other NS and superconducting properties which have been interpreted in terms of the presence of Δ_N in the underdoped region. The rate of depression of T_c due to impurity scattering ($\propto 1/\gamma$ at T_c) remains constant across the overdoped region then rises sharply with the opening of Δ_N , beginning in the lightly overdoped region at $p \sim 0.19$ [21]. Boebinger and coworkers [22] using intense pulsed magnetic fields observe a crossover from insulating to metallic behaviour at $T = 0$ occurring near $p = 0.18$ and angle-resolved photoemission studies show the development, in the overdoped region, of a full NS Fermi surface [23]. In this region the resistivity coefficient, $[\rho(T) - \rho(0)]/T$, exhibits a low-T suppression due to the opening of Δ_N [24]. These considerations provide a compelling motivation for interpreting our penetration depth data within a similar scenario.

The proper means of incorporating the pseudogap effects within a realistic model, and indeed the very nature of the pseudogap is a matter of current debate. However, a key characteristic of Δ_N is the loss of NS spectral weight near E_F . The loss of spectral weight can cause, as discussed above, both a strong reduction in $\rho_s(0)$ and, in a simple model, enhanced curvature in $\rho_s(T)/\rho_s(0)$ above the BCS weak-coupling d-wave T-dependence [25], the very features we observe for the optimal and underdoped samples.

We note that our data are in reasonable agreement with earlier reports for slightly underdoped grain-aligned $\text{HgBa}_2\text{Ca}_2\text{Cu}_3\text{O}_{8+\delta}$ [11,26] and single crystal LSCO with $x = 0.15$ [27]. In contrast to the strong p dependence we have found in $[\lambda_{ab}(0)/\lambda_{ab}(T)]^2$ for LSCO and Hg-1201, studies in YBCO [28,29] reported that $[\lambda_{ab}(0)/\lambda_{ab}(T)]^2$ scaled approximately with $1/T_c$ for various dopings, at all temperatures. However, systematic changes in $[\lambda_{ab}(0)/\lambda_{ab}(T)]^2$ with p were noted at the time [29] although these were too small to allow further analysis. This may simply be due to the fact that the YBCO samples were not as heavily underdoped as the $x = 0.10$ LSCO sample. We also note that YBCO is complicated by a mixed s+d order parameter [1,30] and the effect of the Cu-O chains on the total ρ_s [31,32].

In summary, using the *acs* and μSR techniques we have obtained consistent and systematic results on the effects of carrier concentration on ρ_s of monolayer cuprates. In the overdoped region we find a more or less constant value of $\rho_s(0)$ (up to $p = 0.24$), and $\rho_s(T)/\rho_s(0)$ is in reasonably good agreement with the weak-coupling d-wave T-dependence. In the optimal and underdoped regions $\rho_s(0)$ is rapidly suppressed and above $0.1T_c$ there is a marked departure of $\rho_s(T)/\rho_s(0)$ from the weak-coupling

curve. In a comparative study with available specific heat data we found evidence supporting a link in the behaviour of ρ_s and the normal state gap Δ_N .

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FIG. 1. (a) $\lambda_{ab}^{-2}(T)$ obtained by the ac-susceptibility technique for grain-aligned $\text{La}_{2-x}\text{Sr}_x\text{CuO}_4$ (LSCO) with $x = p = 0.10, 0.15, 0.20, 0.22$ and 0.24 . Data obtained by μSR for unoriented LSCO ($p = 0.10, 0.15$) powders are also included (closed symbols). (b) $\sigma(T) \propto \lambda_{ab}^{-2}(T)$, for $\text{HgBa}_2\text{CuO}_{4+\delta}$ unoriented powders with $\delta = 0.10, 0.154$ and 0.37 ($p = 0.075, 0.17$ and 0.22 , respectively). The data for $\delta = 0.154$ is taken from Ref. [17].

FIG. 2. Low-T $\lambda_{ab}^{-2}(T)$ for $\text{La}_{2-x}\text{Sr}_x\text{CuO}_4$ (LSCO) versus x compared with the low-T specific heat coefficient γ [16]. Inset: $\lambda_{ab}^{-2}(0)$ for LSCO compared with $[S/T(T_c) - S/T(2K)]$ [16].

FIG. 3. (a) $[\lambda_{ab}(0)/\lambda_{ab}(T)]^2$ obtained by the ac-susceptibility technique for grain-aligned $\text{La}_{2-x}\text{Sr}_x\text{CuO}_4$ with $x = p = 0.10, 0.15, 0.20, 0.22$ and 0.24 compared with the weak-coupling BCS theory (solid line) for a d-wave superconductor [18]. (b) The $[\lambda_{ab}(0)/\lambda_{ab}(T)]^2$ data for $x = 0.20, 0.22$ and 0.24 shown in panel (a) but corrected for a distribution of T_c values with standard deviation 3%, 5% and 9% respectively (see text for details). The solid lines are the BCS d-wave T-dependence corrected for the respective distribution in T_c 's. The curves for $x = 0.22$ and 0.24 are shifted vertically for clarity.

Fig. 1(a)

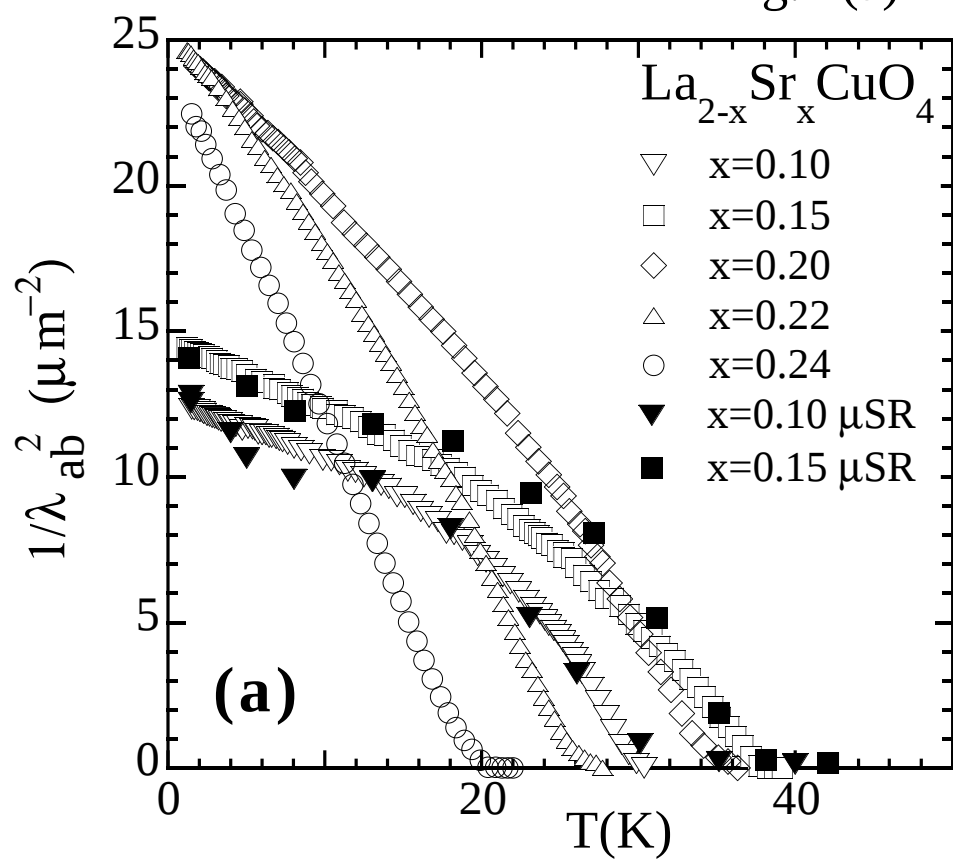
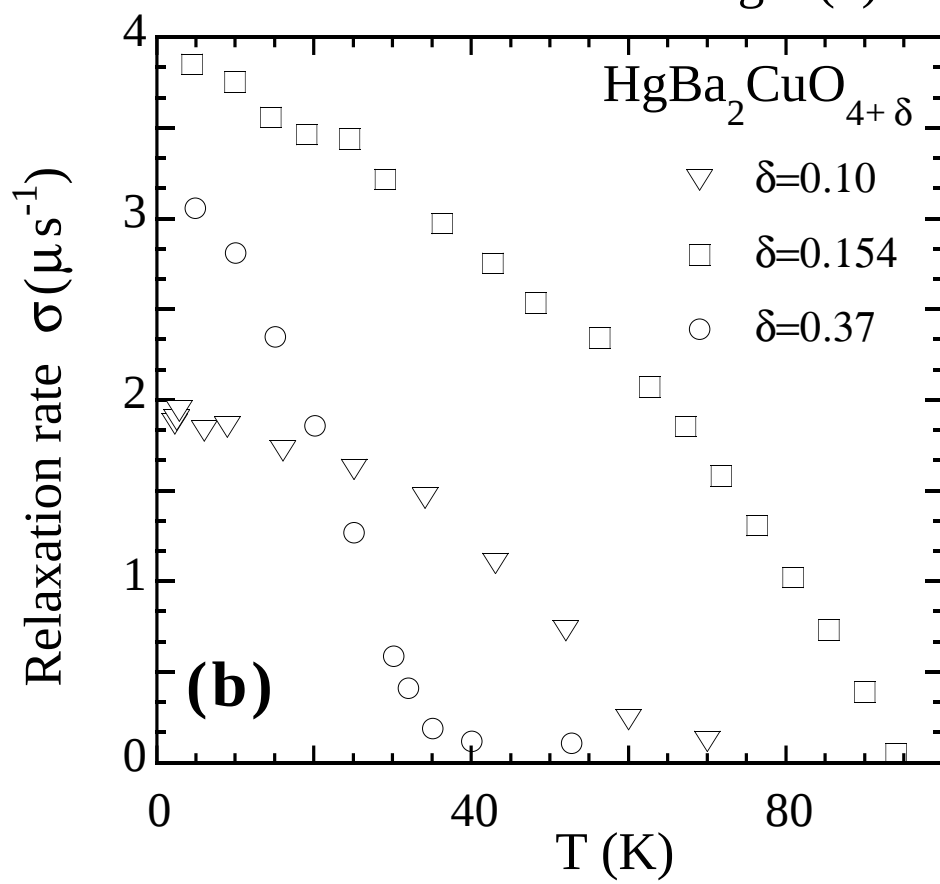


Fig. 1(b)



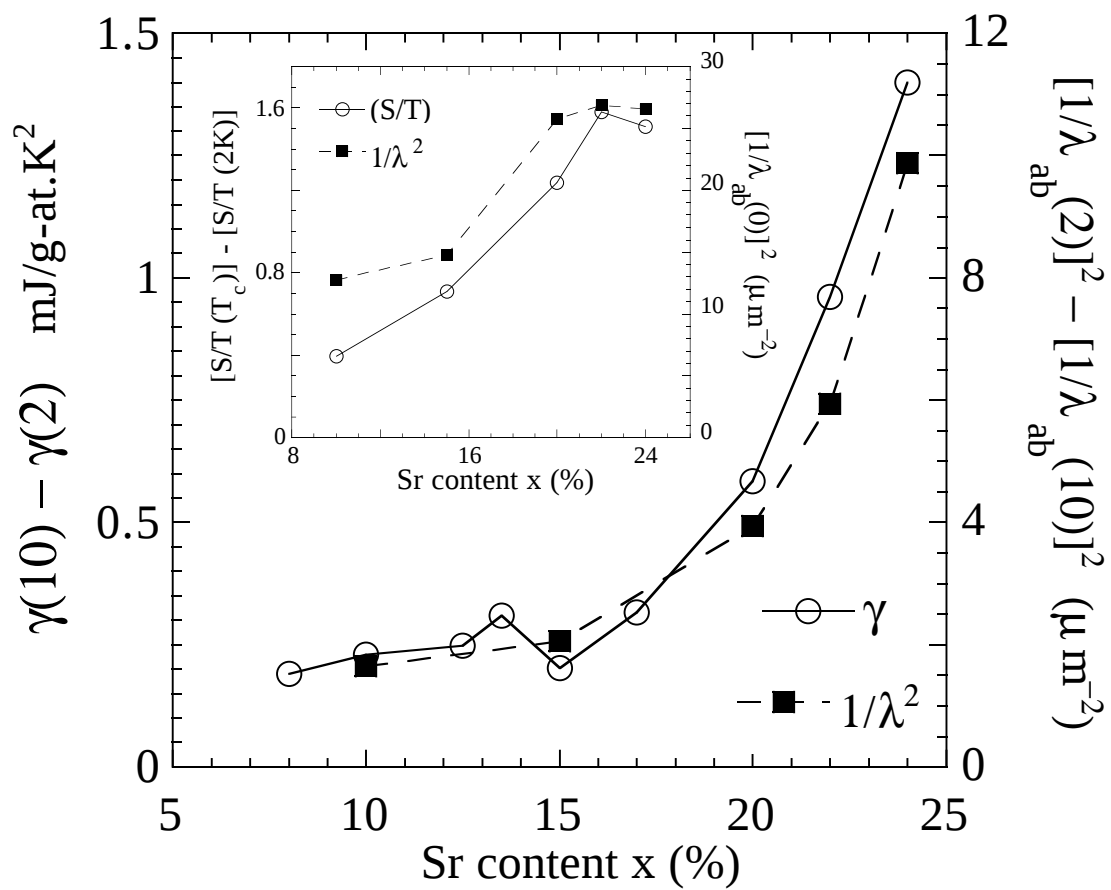


Fig. 3(a)

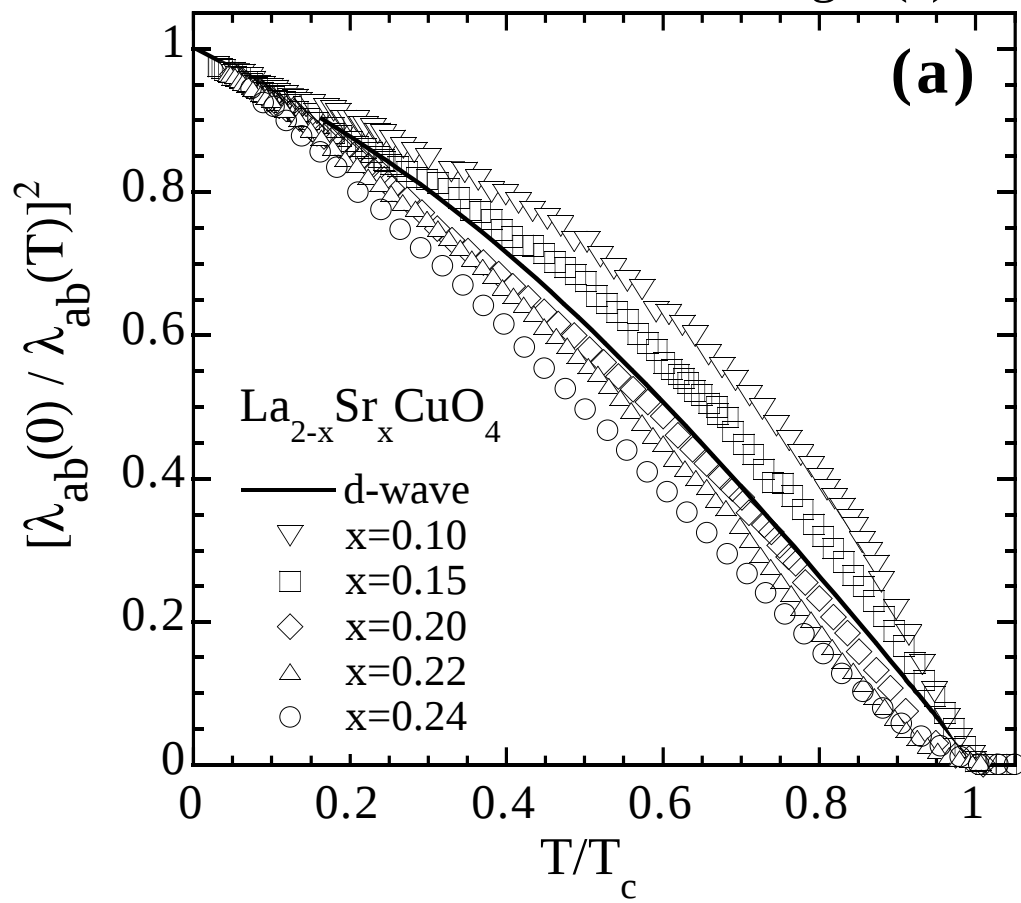


Fig. 3(b)

